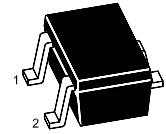


BC856W...BC860W

PNP Silicon Epitaxial Planar Transistor

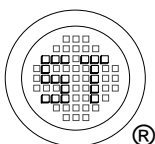
for general purpose and switching applications



1.Base 2.Emitter 3.Collector
SOT-323 Plastic Package

Absolute Maximum Ratings ($T_a = 25\text{ }^\circ\text{C}$)

Parameter	Symbol	Value	Unit		
Collector Base Voltage	$-V_{CBO}$	BC856W BC857W BC858W BC859W BC860W	80 50 30 30 50	V	
Collector Emitter Voltage		$-V_{CEO}$	BC856W BC857W BC858W BC859W BC860W	65 45 30 30 45	V
Emitter Base Voltage			$-V_{EBO}$	5	V
Collector Current			$-I_C$	100	mA
Peak Collector Current			$-I_{CM}$	100	mA
Total Power Dissipation	P_{tot}		200	mW	
Junction Temperature	T_j	150	$^\circ\text{C}$		
Storage Temperature Range	T_s	- 55 to + 150	$^\circ\text{C}$		



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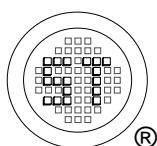


Dated : 21/06/2006

BC856W...BC860W

Characteristics at $T_a = 25\text{ }^\circ\text{C}$

Parameter	Symbol	Min.	Max.	Unit	
DC Current Gain at $-V_{CE} = 5\text{ V}$, $-I_C = 2\text{ mA}$	BC856AW~BC860AW	h_{FE}	125	250	-
	BC856BW~BC860BW	h_{FE}	220	475	-
	BC856CW~BC860CW	h_{FE}	420	800	-
Collector Base Voltage at $-I_C = 10\text{ }\mu\text{A}$	BC856W	$-V_{CBO}$	80	-	V
	BC857W		50	-	
	BC858W		30	-	
	BC859W		30	-	
	BC860W		50	-	
Collector Emitter Voltage at $-I_C = 10\text{ mA}$	BC856W	$-V_{CEO}$	65	-	V
	BC857W		45	-	
	BC858W		30	-	
	BC859W		30	-	
	BC860W		45	-	
Emitter Base Voltage at $-I_E = 1\text{ }\mu\text{A}$	$-V_{EBO}$	5	-	V	
Collector Base Cutoff Current at $-V_{CB} = 30\text{ V}$	$-I_{CBO}$	-	15	nA	
Emitter Base Cutoff Current at $-V_{EB} = 5\text{ V}$	$-I_{EBO}$	-	100	nA	
Collector Emitter Saturation Voltage at $-I_C = 10\text{ mA}$, $-I_B = 0.5\text{ mA}$ $-I_C = 100\text{ mA}$, $-I_B = 5\text{ mA}$	$-V_{CE(sat)}$	-	0.3	V	
		-	0.65		
Base Emitter Voltage at $-V_{CE} = 5\text{ V}$, $-I_C = 2\text{ mA}$ $-V_{CE} = 5\text{ V}$, $-I_C = 10\text{ mA}$	$-V_{BE}$	0.6	0.75	V	
		-	0.82		
Transition Frequency at $-V_{CE} = 5\text{ V}$, $-I_C = 10\text{ mA}$, $f = 100\text{ MHz}$	f_T	100	-	MHz	
Output Capacitance at $-V_{CB} = 10\text{ V}$, $I_E = 0$, $f = 1\text{ MHz}$	C_{ob}	-	4.5	pF	



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Certificate No. 7116



ISO 9001:2000
Certificate No. 0506088

Dated : 21/06/2006

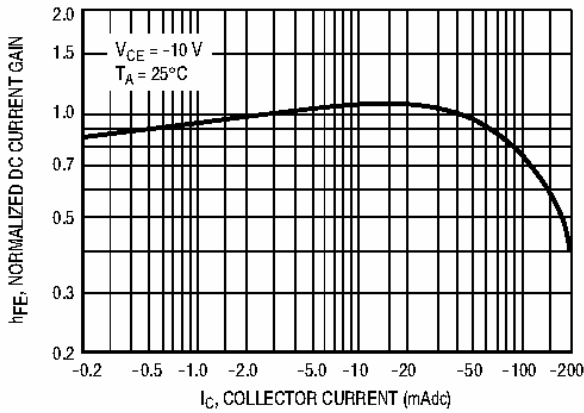


Figure 1. Normalized DC Current Gain

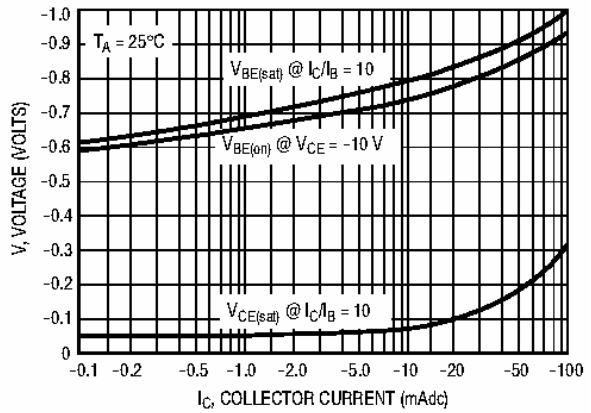


Figure 2. "Saturation" and "On" Voltages

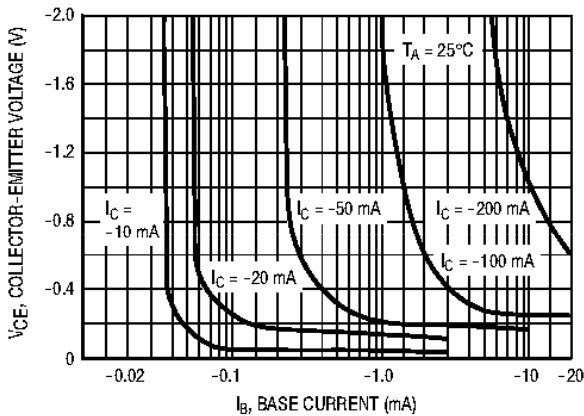


Figure 3. Collector Saturation Region

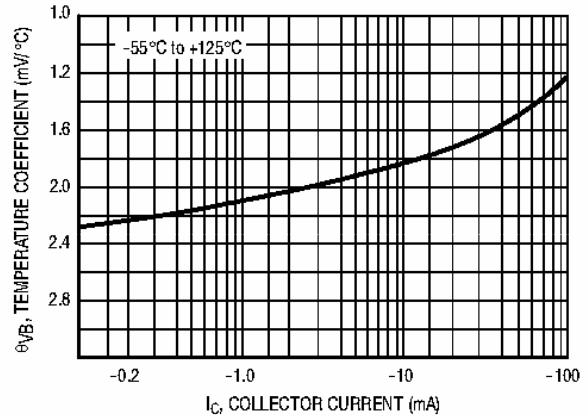


Figure 4. Base-Emitter Temperature Coefficient

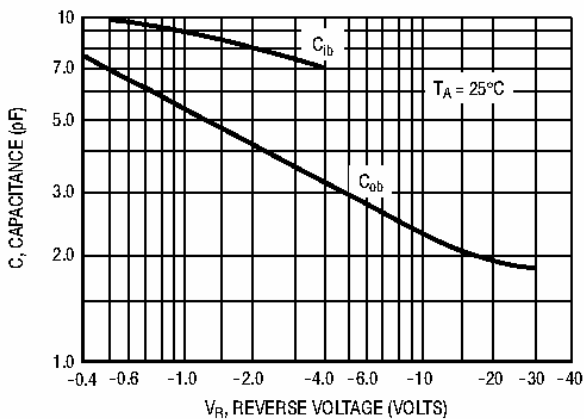


Figure 5. Capacitances

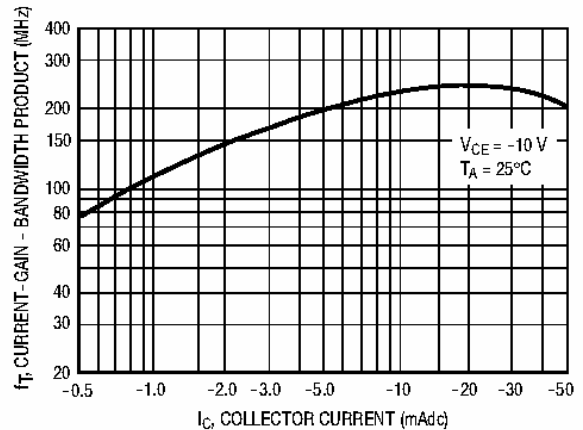
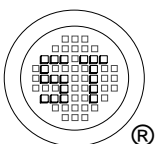


Figure 6. Current-Gain - Bandwidth Product



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BC856W...BC860W

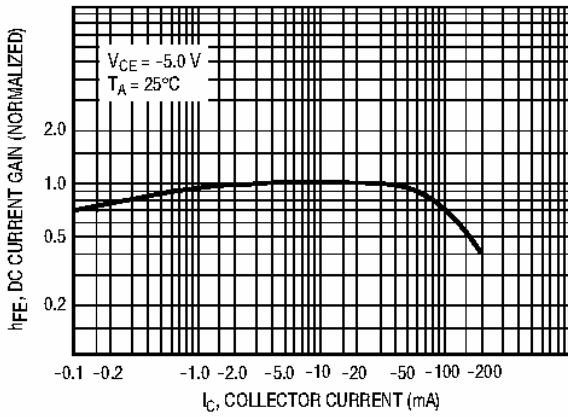


Figure 7. DC Current Gain

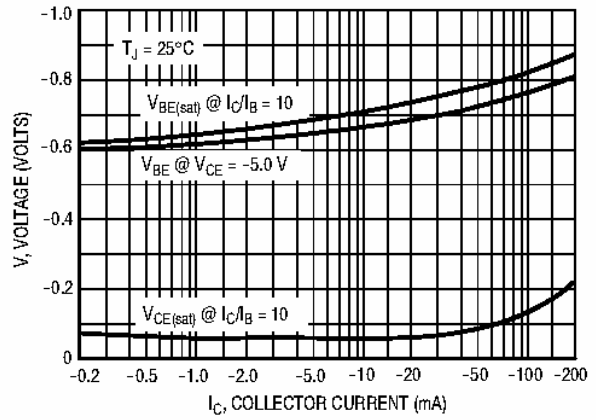


Figure 8. "On" Voltage

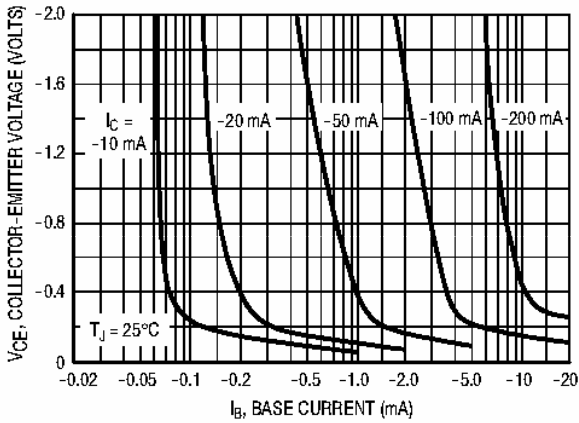


Figure 9. Collector Saturation Region

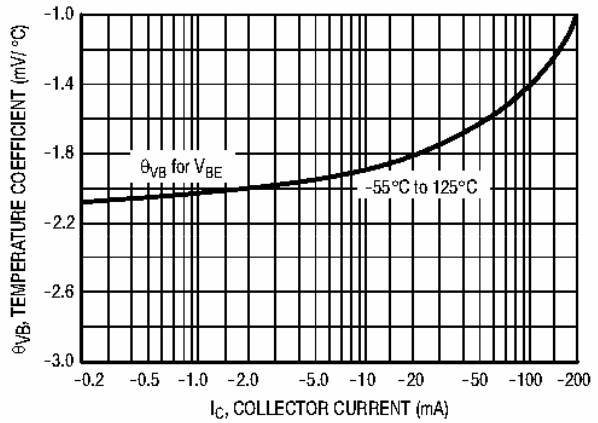


Figure 10. Base-Emitter Temperature Coefficient

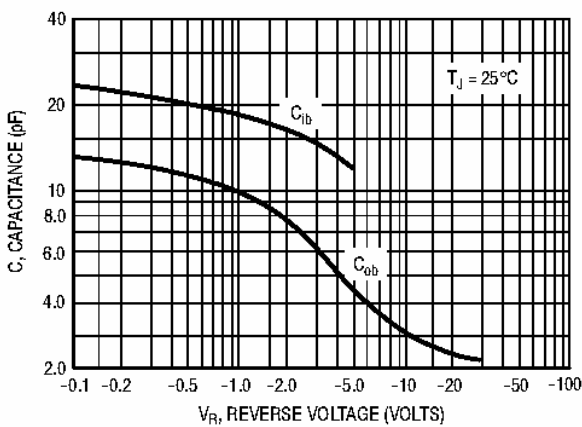


Figure 11. Capacitance

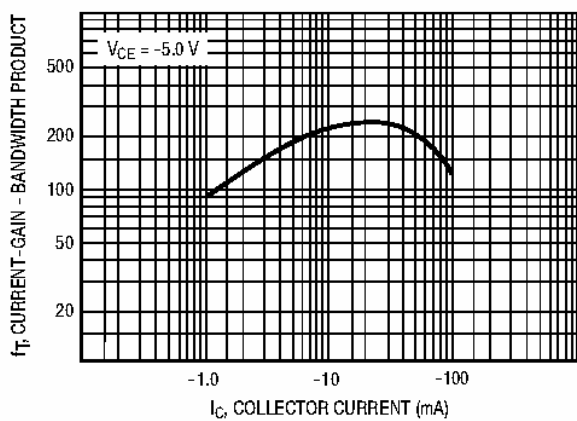
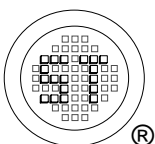


Figure 12. Current-Gain - Bandwidth Product



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